

Approval

## **SPECIFICATION**

**Product: 5mm Green Dome Lamp** 

Part No.: IWL-G5R30F-XXX

Date: 2013. 07. 26 Ver. 2.0

, ,	,	,	,	, , , , ,
		Appro	oved	
Comment				

Proposed By Checked By Checked By Checked By



ITSWELL Co., Ltd 58B-4L, 626-3 Gojan-dong, Namdong-gu, Incheon 405-817 KOREA TEL:+82-32-813-1801, FAX:+82+32-816-1900

URL: http://www.itswell.com

IWL-G5R30F-XXX Version of 2.0 PAGE: 1 / 9



#### 1. Features

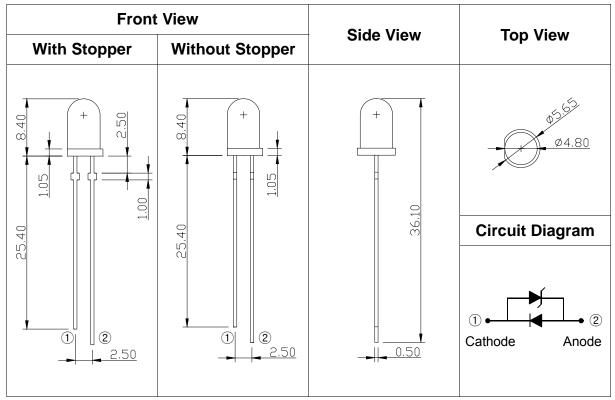
- · Round Type Lamp
- 5mm Resin Mold Type
- · Colored Green
- · Transparency, Diffused or Colored Lens Type
- · High Luminous Intensity
- · Chip Material Based GaN

### 2. Applications

- · Automotive: Backlight in Dashboard and Switch
- Lighting Device: Indicator, Lighting
- · Camera Flash, Hand Carrier Flash
- General Use

### 3. Outline Drawing and Dimension

\* Unit: mm, Tolerance: ±0.5



- \* Note
  - 1. All dimensions are in millimeters
  - 2. All dimensions without tolerances are for reference only
  - 3. Base Material: Fe Alloy
  - 4. Molding : Epoxy5. Lead Plating : Ag/Ni
  - 6. Pb Free

IWL-G5R30F-XXX	Version of 2.0	PAGE: 2 / 9
----------------	----------------	-------------



## 4. Absolute Maximum Ratings (Ta = $25^{\circ}$ C)

Parameter	Symbol	Value	Unit
Power Dissipation	P <sub>d</sub>	105	mW
Continuous Forward Current	I <sub>F</sub>	30	mA
Peak Forward Current *1	I <sub>FP</sub>	100	mA
Operating Temperature	$T_{opr}$	-30 ~ 85	°C
Storage Temperature	$T_{stg}$	-40 ~ 100	°C
Soldering Temperature	$T_{sol}$	260 (5sec)	°C

<sup>\*1</sup> Duty ratio = 1/10, Pulse width = 10ms

### 5. Electrical & Optical Characteristics (Ta = 25 °C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit.
Forward Voltage *2	VF	I <sub>F</sub> = 20 mA	2.8	-	3.5	V
Reverse Voltage	V <sub>R</sub>	I <sub>R</sub> = 5 mA	0.7	0.8	1.5	V
Luminous Intensity *3	l <sub>V</sub>	I <sub>F</sub> = 20 mA	9,900	-	38,000	mcd
Dominant Wavelength **4	$W_D$	I <sub>F</sub> = 20 mA	520	-	535	nm
Viewing angle *5	20 1/2	I <sub>F</sub> = 20 mA	-	30	-	deg.

<sup>\*\*2</sup> Forward Voltage has a tolerance of  $\pm 0.05 \text{ V}$ .

#### **5.1 Luminous Intensity Rank**

Rank	Luminous Intensity (mcd)
U	9900 ~ 13000
V	13000 ~ 17000
W	17000 ~ 22000
Y	22000 ~ 29000
Z	29000 ~ 38000

### **5.2 Forward Voltage Rank**

Rank	Forward Voltage (V)
1	2.8 ~ 3.2
2	3.2 ~ 3.5

#### **5.3 Dominant Wavelength Rank**

Rank	Dominant Wavelength (nm)
В	520 ~ 525
С	525 ~ 530
D	530 ~ 535

IWL-G5R30F-XXX Ver	rsion of 2.0 PAGE: 3 / 9
--------------------	--------------------------

<sup>\*3</sup> Luminous Intensity is measured with an integrating sphere and has an accuracy of 10%.

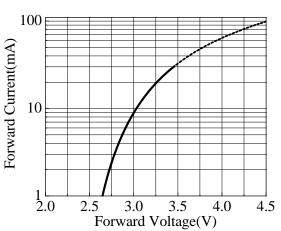
<sup>\*\*4</sup> Dominant Wavelength has an accuracy of ±2nm

<sup>\*5</sup> Viewing Angle is the angle until 50% of brightness measured from the front part of LED.



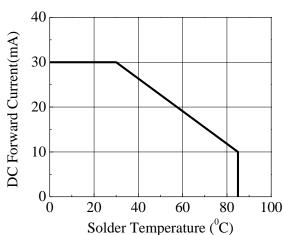
## 6. Typical Characteristic Curve

## Forward Current vs. Forward Voltage

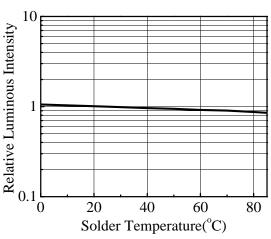


Forward Current vs. Solder Temperature

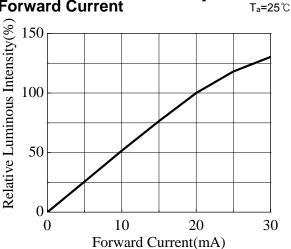
Ta=25 ℃



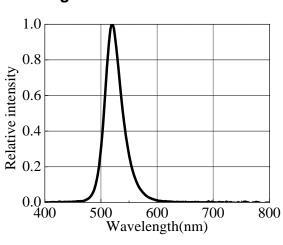
Relative Luminous Intensity vs. Solder Temperature



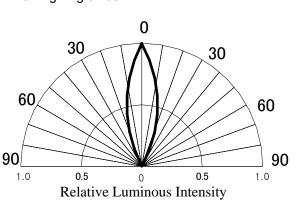
Relative Luminous Intensity vs. Forward Current



Relative Luminous Intensity vs. T<sub>a</sub>=25 °C I<sub>F</sub>=20mA



**Radiation Diagram** 



T<sub>a</sub>=25 ℃ I<sub>F</sub>=20mA

- Viewing Angle: 30°

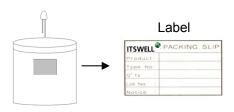
IWL-G5R30F-XXX Version of 2.0 PAGE: 4 / 9



## 7. Packing & Tapping Dimension

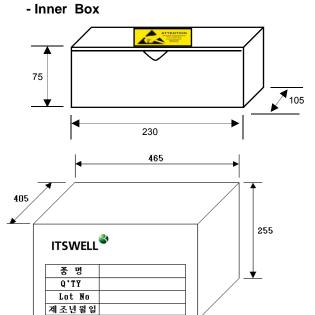
#### 7.1 Bulk Packing

#### - Bag packing



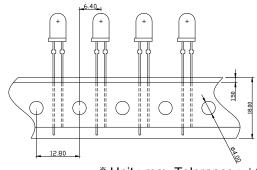
#### - Out Packing

- Maximum Inner Box 20 / 1 Box 30,000 pcs/ 1 Box
- Out box material : Carton



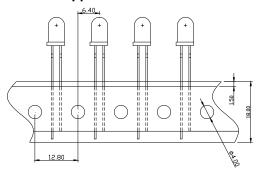
#### 7.2 Tapping Packing

#### - With Stopper



\* Unit: mm, Tolerance: ±0.5

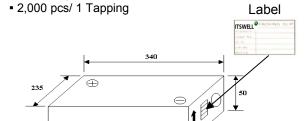
#### - Without Stopper



\* Unit : mm, Tolerance :  $\pm 0.5$ 

#### - Taping Box

- Tapping Box (Carton)
- 1 Tapping Box / Pack with Silica Gel



#### - Out Box

- Maximum 10 Tapping Box / Box

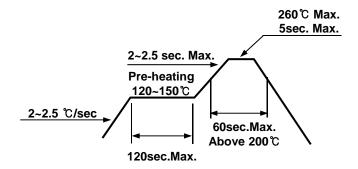
제 조년 윌일



#### 8. Precaution in use

#### 8.1 Soldering Conditions

- When soldering DIP LED , Heat may affect the electrical and optical characteristics of the LEDs.
- In soldering, do not stress the lead frame and the resin part under the high temperature.
- The epoxy part should be protected from mechanical stress or vibration until the DIP LEDs return to room temperature after soldering.
- Preliminary heating to be at 120~150 °C max. for 120 Seconds max.
- Soldering heat to be at 260 °C max. for 5sec. Max.
- For manual Soldering is Not more than 3sec @MAX350°C, under soldering iron



#### 8.2 Storage

■ Use with 7days after opening packing. Store in 10 to 30 °C DIP LED lead frames are plated Silver. The silver surface may be affected by environment which contain corrosive gases and so on. Please avoid condition which may cause the DIP LED to corroded, tarnish or discolor.

#### 8.3 Static Electricity

- Static electricity or surge voltage damages the DIP LEDs. It is recommended that a wrist band or an anti-electrostatic glove be used when handling the LEDs.
- A tip soldering iron is requested to be grounded. An ionizer should also be installed where risk of static.
- All devices, equipment and machinery must be properly grounded (via  $1M\Omega$ ). It is recommended that measures be taken against surge voltage to the equipment that mounts the DIP LEDs.

#### 8.4 Cleaning

- Isopropyl Alcohol or Ethylene Alcohol is recommended in 5 minutes at room temperature.
   Don't use unspecified chemical may cause crack or haze on the surface of the epoxy resin.
- Before cleaning, a pre-test should be done to confirm whether any damage to the DIP LED will occur.
- Freon solvents should not be used to clean the DIP LEDs because of worldwide regulations.

IWL-G5R30F-XXX Version of 2.0 PAGE: 6 / 9



## 9. Reliability

### 9.1 Reliability Test Item

Test Items	Test Conditions	Notes
High Temperature Storage	100°C, 1,000hr.	0/20
Low Temperature Storage	-40°C, 1,000hr.	0/20
Temp. Humidity Storage	60°C, 90% RH, 1,000hr.	0/20
Steady State Operating life	25°C, 30mA , 1,000hr.	0/20
High Temperature Operating Life	85°C, 10mA, 1,000hr.	0/20
Low Temperature Operating Life	-30°C, 20mA, 1,000hr.	0/20
Steady State Operating life Of High Humidity Heat	60°C, 90% RH, 15mA, 1,000hr.	0/20
Thermal Shock	-40°c (30min) ↔ 100°c (30min.), 100 cycle	0/20
ESD	HBM, 100 pF, 1.5 kΩ, 3 times	0/20

### 9.2 Criteria for Judging the Damage

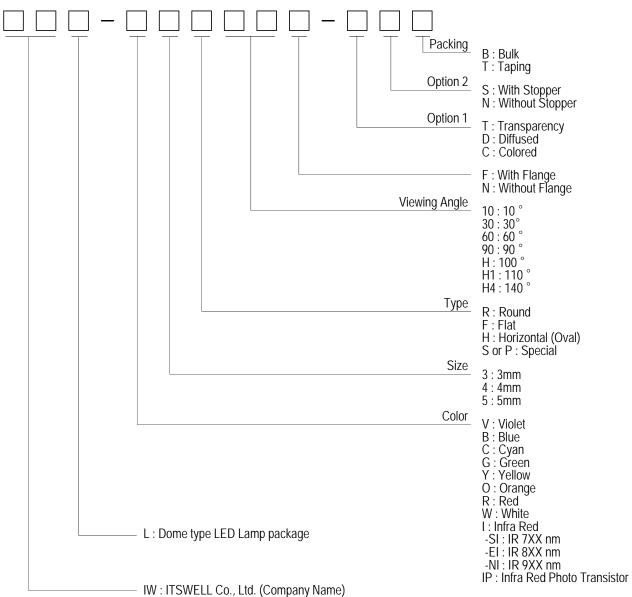
Items	Test Conditions	Criteria for judgment	
Luminous Intensity ( I <sub>V</sub> )	I <sub>F</sub> = 20mA	> 70% of S	
Forward Voltage (V <sub>F</sub> )	I <sub>F</sub> = 20mA	Less than 110% of U	

<sup>\*</sup> U means the upper limit of specified characteristics, S means initial value.

IWI_C5D30F_YYY	Version of 2.0	PACE • 7 / 0
IWL-G5R30F-XXX	Version of 2.0	PAGE: 7 / 9



### 10. Part Name Description



## 11. Attention : Electric Static Discharge (ESD) Protection



FOR HANDLING
ELECTROSTATIC DISCHARGE
SENSITIVE DEVICES

The symbol shown on the page herein to introduce 'Electro-Optical Characteristics'. ESD protection for GaP and AlGaAs is based chips is still necessary even though they are safe in low static-electric discharge. Material in AllnGaP, GaP, or/and InGaN based chips are STATIC SENSITIVE devices. ESD protection has to considered and taken in the initial design stage.If manual work/process is needed, please ensure the device is well protective from ESD during all the process.

IWL-G5R30F-XXX	Version of 2.0	PAGE: 8 / 9



## **■** Spec. Review History

Review Ver.	Date	Correction List	Etc.
Ver 1.0	2006.06.19	Establish	
Ver 1.1	2008.06.10	Revision	
Ver 2.0	2013.07.26	Revision	

IWL-G5R30F-XXX	Version of 2.0	PAGE: 9 / 9
----------------	----------------	-------------